

DS5001FP 128k Soft Microprocessor Chip

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FEATURES

- 8051-Compatible Microprocessor Adapts to Its Task
 - Accesses up to 128kB of nonvolatile SRAM
 - In-system programming through on-chip serial port
 - Can modify its own program or data memory
 - Accesses memory on a separate byte-wide bus
 - Performs CRC-16 check of NV RAM memory
 - Decodes memory and peripheral chip enables

High-Reliability Operation

- Maintains all nonvolatile resources for over 10 years
- Power-fail reset
- Early warning power-fail interrupt
- Watchdog timer
- Lithium backs user SRAM for program/data storage
- Precision bandgap reference for power monitor
- Fully 8051 Compatible
 - 128kB scratchpad RAM
 - Two timer/counters
 - On-chip serial port
 - 32 parallel I/O port pins
- Software Security Available with DS5002FP Secure Microprocessor

This data sheet must be used in conjunction with the Secure Microcontroller User's Guide, available on our website at <u>www.maxim-ic.com/microcontrollers</u>. The user's guide contains operating information, whereas the data sheet contains ordering information, pinout, and electrical specifications

PIN CONFIGURATIONS



Note: Some revisions of this device may incorporate deviations from published specifications known as errata. Multiple revisions of any device may be simultaneously available through various sales channels. For information about device errata, click here: <u>www.maxim-ic.com/errata</u>.

ORDERING INF	ORIMATION		
PART	TEMP RANGE	MAX CLOCK SPEED (MHz)	PIN- PACKAGE
DS5001FP-16	0° C to $+70^{\circ}$ C	16	80 MQFP
DS5001FP-16+	0° C to $+70^{\circ}$ C	16	80 MQFP
DS5001FP-16N	-40°C to +85°C	16	80 MQFP
DS5001FP-16N+	-40°C to +85°C	16	80 MQFP
DS5001FP-12-44	0° C to $+70^{\circ}$ C	12	44MQFP
DS5001FP-12-44+	0° C to $+70^{\circ}$ C	12	44 MQFP

ORDERING INFORMATION

+ Denotes a Pb-free/RoHS-compliant device.

DESCRIPTION

The DS5001FP 128k soft microprocessor chip is an 8051-compatible microprocessor based on NV RAM technology and designed for systems that need large quantities of nonvolatile memory. It provides full compatibility with the 8051 instruction set, timers, serial port, and parallel I/O ports. By using NV RAM instead of ROM, the user can program and then reprogram the microprocessor while in-system. The application software can even change its own operation, which allows frequent software upgrades, adaptive programs, customized systems, etc. In addition, by using NV SRAM, the DS5001FP is ideal for data logging applications. It also connects easily to a Dallas real-time clock.

The DS5001FP provides the benefits of NV RAM without using I/O resources. It uses a nonmultiplexed byte-wide address and data bus for memory access. This bus performs all memory access and provides decoded chip enables for SRAM, which leaves the 32 I/O port pins free for application use. The DS5001FP uses ordinary SRAM and battery-backs the memory contents for over 10 years at room temperature with a small external battery. A DS5001FP also provides high-reliability operation in harsh environments. These features include the ability to save the operating state, power-fail reset, power-fail interrupt, and watchdog timer.

A user programs the DS5001FP through its on-chip serial bootstrap loader. The bootstrap loader supervises the loading of software into NV RAM, validates it, and then becomes transparent to the user. Software can be stored in multiple 32kB or one 128kB CMOS SRAM(s). Using its internal partitioning, the DS5001FP can divide a common RAM into user-selectable program and data segments. This partition can be selected at program loading time, but can then be modified later at any time. The microprocessor decodes memory access to the SRAM and addresses memory through its byte-wide bus. Memory portions designated code or ROM are automatically write-protected by the microprocessor. Combining program and data storage in one device saves board space and cost.

The DS5001FP offers several bank switches for access to even more memory. In addition to the primary data area of 64kB, a peripheral selector creates a second 64kB data space with four accompanying chip enables. This area can be used for memory-mapped peripherals or more data storage. The DS5001FP can also use its expanded bus on ports 0 and 2 (like an 8051) to access an additional 64kB of data space. Lastly, the DS5001FP provides one additional bank switch that changes up to 60kB of the NV RAM program space into data memory. Thus, with a small amount of logic, the DS5001 accesses up to 252kB of data memory.

The DS2251T is available (Refer to the data sheet at <u>www.maxim-ic.com/microcontrollers</u>.) for users who want a preconstructed module using the DS5001FP, RAM, lithium cell, and a real-time clock. For more details, refer to the *Secure Microcontroller User's Guide*. For users desiring software security, the DS5002FP is functionally identical to the DS5001FP but provides superior firmware security. The 44-pin version of the device is functionally identical to the 80-pin version but sports a reduced pin count and footprint.

Figure 1. BLOCK DIAGRAM



PIN DESCRIPTION

PIN B0 PINNAMEFUNCTION11, 97, 7, 75 77, 7531 (P0.5)P0.0- P0.7General-Purpose I/O Port 0. This port is open-drain and cannot drive a logic 1. It requires external pullups. Port 0 is also the multiplexed expanded address/data bus. When used in this mode, it does not require pullups.15, 17, 77, 75 92, 31P1.0- P1.7General-Purpose I/O Port 125, 27, 7 93, 31P1.0- P2.7General-Purpose I/O Port 139, 31P1.0- P2.7General-Purpose I/O Port 1. Also serves as the MSB of the address in expanded memory accesses, and as pins of the RPC mode when used.3810P3.1/TX DGeneral-Purpose I/O Port Pin 3.0. Also serves as the receive signal for the on board UART. This pin should <i>not</i> be connected directly to a PC COM port.39P3.2/ P3.1/TXGeneral-Purpose I/O Port Pin 3.1. Also serves as the transmit signal for the on board UART. This pin should <i>not</i> be connected directly to a PC COM port.39P3.2/TX General-Purpose I/O Port Pin 3.2. Also serves as the transmit signal for the on board UART. This pin should <i>not</i> be connected directly on a PC COM port.4011F3.3/TB FSTTIGeneral-Purpose I/O Port Pin 3.4. Also serves as the cative-low external interrupt 0.41P3.4/T0General-Purpose I/O Port Pin 3.4. Also serves as the timer 0 input.4412P3.5/TIGeneral-Purpose I/O Port Pin A. Also serves as the timer 0 input.46P3.7/RBGeneral-Purpose I/O Port Pin. Also serves as the timer 0 input.47-P3.6/WRGeneral-Purpose I/O Port Pin. Also serves as the	DIN			
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1238 V_{CCO} The lithium cell remains isolated from a load. When V_{CC} is below V_{LI} , the V_{CCO} switches to the V_{LI} source. V_{CCO} should be connected to the V_{CC} pin of an SRAM.5417VerLithium Voltage Input. Connect to a lithium cell greater than V_{LIMIN} and no greater				
5417VerLithium Voltage Input. Connect to a lithium cell greater than V_{LIMIN} and no greater	12	38	V _{CCO}	
54 17 Ver Lithium Voltage Input. Connect to a lithium cell greater than V _{LIMIN} and no greater			220	
than v_{LImax} as shown in the electrical specifications. Nominal value is +3 V.	54	17	$\mathbf{V}_{\mathbf{L}\mathbf{I}}$	
				than v_{LImax} as shown in the electrical specifications. Nominal value is $+3V$.

PIN DESCRIPTION (continued)

P	PIN NAME EUNCTION		
80 PIN	44 PIN	NAME	FUNCTION
53, 16, 8, 18, 80, 76, 4, 6, 20, 24, 26, 28, 30, 33, 35, 37	41, 36, 42, 32, 30, 34, 35, 43, 1, 2, 3, 4, 5, 7, 9	BA14– BA0	Byte-Wide Address Bus Bits 14–0 . This bus is combined with the nonmultiplexed data bus (BD7–0) to access NV SRAM. Decoding is performed using $\overline{CE1}$ through $\overline{CE4}$. Therefore, BA15 is not actually needed. Read/write access is controlled by R/ \overline{W} . BA14–0 connect directly to an 8k, 32k, or 128k SRAM. If an 8k RAM is used, BA13 and BA14 are unconnected. If a 128k SRAM is used, the micro converts $\overline{CE2}$ and $\overline{CE3}$ to serve as A16 and A15 respectively.
71, 69, 67, 65, 61, 59, 57, 55	28, 26, 24, 23, 21, 20, 19, 18	BD7–0	Byte-Wide Data Bus Bits 7–0 . This 8-bit, bidirectional bus is combined with the nonmultiplexed address bus (BA14–0) to access NV SRAM. Decoding is performed on $\overline{CE1}$ and $\overline{CE2}$. Read/write access is controlled by R/\overline{W} . BD7–0 connect directly to an SRAM, and optionally to a real-time clock or other peripheral.
10	37	$\mathbf{R}/\overline{\mathbf{W}}$	Read/Write. This signal provides the write enable to the SRAMs on the byte-wide bus. It is controlled by the memory map and partition. The blocks selected as program (ROM) are write-protected.
74	29	CE1	Chip Enable 1. This is the primary decoded chip enable for memory access on the byte-wide bus. It connects to the chip enable input of one SRAM. \overline{CEI} is lithium-backed. It remains in a logic high inactive state when V_{CC} falls below V_{LI} .
72		CE1N	Non-Battery-Backed Version of Chip Enable 1. This can be used with a 32kB EPROM. It should not be used with a battery-backed chip.
2	33	CE2	Chip Enable 2. This chip enable is provided to access a second 32k block of memory. It connects to the chip enable input of one SRAM. When MSEL = 0, the micro converts $\overline{CE2}$ into A16 for a 128k x 8 SRAM. $\overline{CE2}$ is lithium-backed and remains at a logic high when V _{CC} falls below V _{LI} .
63	22	CE3	Chip Enable 3. This chip enable is provided to access a third 32k block of memory. It connects to the chip enable input of one SRAM. When $MSEL = 0$, the micro converts $\overline{CE3}$ into A15 for a 128k x 8 SRAM. $\overline{CE3}$ is lithium-backed and remains at a logic high when V_{CC} falls below V_{LI} .
62	_	CE4	Chip Enable 4. This chip enable is provided to access a fourth 32k block of memory. It connects to the chip-enable input of one SRAM. When $MSEL = 0$, this signal is unused. $\overline{CE4}$ is lithium-backed and remains at a logic high when $V_{CC} < V_{LI}$.
78		PE1	Peripheral Enable 1. Accesses data memory between addresses 0000h and 3FFFh when the PES bit is set to a logic 1. Commonly used to chip enable a byte-wide real-time clock such as the DS1283. $\overline{PE1}$ is lithium-backed and remains at a logic high when V_{CC} falls below V_{LI} . Connect $\overline{PE1}$ to battery-backed functions only.
3		PE2	Peripheral Enable 2. Accesses data memory between addresses 4000h and 7FFFh when the PES bit is set to a logic 1. $\overrightarrow{PE2}$ is lithium-backed and remains at a logic high when V _{CC} falls below V _{LI} . Connect $\overrightarrow{PE2}$ to battery-backed functions only.
22		PE3	Peripheral Enable 3. Accesses data memory between addresses 8000h and BFFFh when the PES bit is set to a logic 1. $\overline{PE3}$ is not lithium-backed and can be connected to any type of peripheral function. If connected to a battery-backed chip, it needs additional circuitry to maintain the chip enable in an inactive state when $V_{CC} < V_{LI}$.
23		PE4	Peripheral Enable 4. Accesses data memory between addresses C000h and FFFFh when the PES bit is set to a logic 1. $\overrightarrow{PE4}$ is not lithium-backed and can be connected to any type of peripheral function. If connected to a battery-backed chip, it needs additional circuitry to maintain the chip enable in an inactive state when $V_{CC} < V_{LI}$.
32		PROG	Invokes the bootstrap loader on a falling edge. This signal should be debounced so that only one edge is detected. If connected to ground, the micro enters bootstrap loading on power-up. This signal is pulled up internally.

PI	N	NAME	FUNCTION		
80 PIN 44 PIN			FUNCTION		
42		VRST	This I/O pin (open drain with internal pullup) indicates that the power supply (V_{CC}) has fallen below the V_{CCmin} level and the micro is in a reset state. When this occurs, the DS5001FP drives this pin to a logic 0. Because the micro is lithium-backed, this signal is guaranteed even when $V_{CC} = 0V$. Because it is an I/O pin, it also forces a reset if pulled low externally. This allows multiple parts to synchronize their power-down resets.		
43		PF	This output goes to a logic 0 to indicate that $V_{CC} < V_{LI}$ and the micro has switched to lithium backup. Because the micro is lithium-backed, this signal is guaranteed even when $V_{CC} = 0V$. The normal application of this signal is to control lithium-powered current to isolate battery-backed functions from non-battery-backed functions.		
14	40	MSEL	Memory Select. This signal controls the memory size selection. When $MSEL = +5V$, the DS5001FP expects to use 32k x 8 SRAMs. When $MSEL = 0V$, the DS5001FP expects to use a 128k x 8 SRAM. MSEL must be connected regardless of partition, mode, etc.		
73		N.C.	No Connection		

PIN DESCRIPTION (continued)

INSTRUCTION SET

The DS5001FP executes an instruction set that is object code-compatible with the industry standard 8051 microcontroller. As a result, software development packages such as assemblers and compilers that have been written for the 8051 are compatible with the DS5001FP. A complete description of the instruction set and operation are provided in the *Secure Microcontroller User's Guide*. Also note that the DS5001FP is embodied in the DS2251T module. The DS2251T combines the DS5001FP with between 32k and 128k of SRAM, a lithium cell, and a real-time clock. This is packaged in a 72-pin SIMM module.

MEMORY ORGANIZATION

Figure 2 illustrates the memory map accessed by the DS5001FP. The entire 64k of program and 64k of data are potentially available to the byte-wide bus. This preserves the I/O ports for application use. The user controls the portion of memory that is actually mapped to the byte-wide bus by selecting the program range and data range. Any area not mapped into the NV RAM is reached by the expanded bus on ports 0 and 2. An alternate configuration allows dynamic partitioning of a 64k space as shown in Figure 3. Selecting PES=1 provides another 64k of potential data storage or memory-mapped peripheral space as shown in Figure 4. These selections are made using special function registers. The memory map and its controls are covered in detail in the *Secure Microcontroller User's Guide*.



7 of 27







Figure 4. MEMORY MAP WITH PES = 1

Figure 5 illustrates a typical memory connection for a system using a 128kB SRAM. Note that in this configuration, both program and data are stored in a common RAM chip Figure 6 shows a similar system with using two 32kB SRAMs. The byte-wide address bus connects to the SRAM address lines. The bidirectional byte-wide data bus connects the data I/O lines of the SRAM.



Figure 5. CONNECTION TO 128k x 8 SRAM



Figure 6. DS5001FP CONNECTION TO 64k x 8 SRAM

POWER MANAGEMENT

The DS5001FP monitors V_{CC} to provide power-fail reset, early warning power-fail interrupt, and switch over to lithium backup. It uses an internal bandgap reference in determining the switch points. These are called V_{PFW} , V_{CCMIN} , and V_{LI} , respectively. When V_{CC} drops below V_{PFW} , the DS5001FP performs an interrupt vector to location 2Bh if the power-fail warning was enabled. Full processor operation continues regardless. When power falls further to V_{CCMIN} , the DS5001FP invokes a reset state. No further code execution is performed unless power rises back above V_{CCMIN} . All decoded chip enables and the R/\overline{w} signal go to an inactive (logic 1) state. V_{CC} is still the power source at this time. When V_{CC} drops further to below V_{LI} , internal circuitry switches to the lithium cell for power. The majority of internal circuits are disabled and the remaining nonvolatile states are retained. Any devices connected V_{CCO} are powered by the lithium cell at this time. V_{CCO} is at the lithium battery voltage minus approximately 0.45V. This drop varies depending on the load. Low power SRAMs should be used for this reason. When using the DS5001FP, the user must select the appropriate battery to match the RAM data retention current and the desired backup lifetime. Note that the lithium cell is only loaded when $V_{CC} < V_{LI}$. The *User's Guide* has more information on this topic. The trip points V_{CCMIN} and V_{PFW} are listed in the *Electrical Specifications* section.

ABSOLUTE MAXIMUM RATINGS

Voltage Range on Any Pin Relative to Ground	0.3V to $(V_{CC} + 0.5V)$
Voltage Range on V _{CC} Related to Ground	-0.3V to 6.0V
Operating Temperature Range	-40°C to +85°C
Storage Temperature Range (Note 1)	55°C to +125°C
Soldering Temperature	See IPC/JEDEC J-STD-020 Specification

This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

Note 1: Storage temperature is defined as the temperature of the device when $V_{CC} = 0V$ and $V_{LI} = 0V$. In this state, the contents of SRAM are not battery-backed and are undefined.

DC CHARACTERISTICS

PARAMETER **SYMBOL** MIN ТҮР MAX UNITS NOTES Input Low Voltage -0.3 +0.8V V_{IL} Input High Voltage $\overline{V_{CC}} + 0.3$ 2.0 V 1 V_{IH1} Input High Voltage 3.5 $V_{CC} + 0.3$ V 1 V_{IH2} $(RST, XTAL1, \overline{PROG})$ Output Low Voltage V_{OL1} 0.15 0.45 V 1, 11 at $I_{OL} = 1.6 \text{mA}$ (Ports 1, 2, 3, \overline{PF}) Output Low Voltage at $I_{OL} = 3.2$ mA (Ports 0, ALE, PSEN, V_{OL2} 0.15 0.45 V 1 BA15–0, BD7–0, R/\overline{W} , $\overline{CE1N}$, CE 1-4, PE 1-4, V_{RST}) Output High Voltage V_{OH1} 2.4 V 4.8 1 at $I_{OH} = -80 \mu A$ (Ports 1, 2, 3) Output High Voltage at $I_{OH} = -400 \mu A$ (Ports 0, ALE, PSEN, 2.4 V_{OH2} 4.8 V 1 \overline{PF} , BA15–0, BD7–0, R/ \overline{W} , $\overline{CE1N}$, $\overline{\text{CE}}$ 1–4, $\overline{\text{PE}}$ 1–4, V_{RST}) Input Low Current -50 $I_{\rm IL}$ μA $V_{IN} = 0.45V$ (Ports 1, 2, 3) Transition Current; 1 to 0 $V_{IN} = 2.0V$ (Ports 1, 2, 3) I_{TL} -500 μA $(0^{\circ}C \text{ to } +70^{\circ}C)$ Transition Current; 1 to 0 $V_{IN} = 2.0V$ (Ports 1, 2, 3) -600 10 I_{TL} μA $(-40^{\circ}C \text{ to } +85^{\circ}C)$

 $(V_{CC} = 5V \pm 10\%, T_A = 0^{\circ}C \text{ to } +70^{\circ}C.)$

DC CHARACTERISTICS (continued) $(V_{CC} = 5V \pm 10\%, T_A = 0^{\circ}C \text{ to } +70^{\circ}C.)$

PAR	$\frac{1}{2} = 0 C to + 70 C$	SYMBOL	MIN	ТҮР	MAX	UNITS	NOTES
Input Leakage Cu		I_{IL}			+10	μΑ	
$0.45 < V_{IN} < V_{CC}$ RST Pulldown Re							
$(0^{\circ}C \text{ to } +70^{\circ}C)$	SISTOL	R _{RE}	40		150	kΩ	
RST Pulldown Re	esistor		20		100	1.0	10
(-40°C to +85°C)		R_{RE}	30		180	kΩ	10
VRST Pullup Res	sistor	R _{VR}		4.7		kΩ	
PROG Pullup Res	sistor	R _{PR}		40		kΩ	
Power-Fail Warni (0°C to +70°C)	ng Voltage	V _{PFW}	4.25	4.37	4.50	V	1
Power-Fail Warni (-40°C to +85°C)	ng Voltage	V _{PFW}	4.1	4.37	4.6	V	1, 10
Minimum Operation (0°C to +70°C)		V _{CCMIN}	4.00	4.12	4.25	V	1
Minimum Operation (-40°C to +85°C)	ng Voltage	V _{CCMIN}	3.85	4.09	4.25	V	1, 10
Operating Voltage		V _{CC}	V _{CCMIN}		5.5	V	1
Lithium Supply V	oltage	V_{LI}	2.5		4.0	V	1
Operating Current		I _{CC}			36	mA	2
Idle Mode Curren $(0^{\circ}C \text{ to } +70^{\circ}C)$	t at 12MHz	I _{IDLE}			7.0	mA	3
Idle Mode Curren $(-40^{\circ}C \text{ to } +85^{\circ}C)$	t at 12MHz	I _{IDLE}			8.0	mA	3, 10
Stop Mode Curren	at	I _{STOP}			80	μA	1
Pin Capacitance	11	C _{IN}			10	pF	4 5
Output Supply Vo	oltage (V _{CCO})	V _{CC01}	V _{CC} -0.45			V	1, 2
Output Supply Ba (V_{CCO} , \overline{CE} 1-4, \overline{PI} (0°C to +70°C)	ttery-Backed Mode E 1-2)	V _{CCO2}	V _{LI} -0.65			V	1, 8
$(V_{CCO}, \overline{CE} 1-4, \overline{PI})$ (-40°C to +85°C)		V _{CCO2}	V _{LI} -0.9			V	1, 8, 10
Output Supply Current at $V_{CCO} = V_{CC} - 0.45V$		I _{CCO1}			75	mA	6
Lithium-Backed Quiescent Current (0°C to +70°C)		I _{LI}		5	75	nA	7
Lithium-Backed ((-40°C to +85°C)	-	I _{LI}		75	500	nA	7
	With BAT = $3.0V$ (0°C to +70°C)		4.0		4.25		1
Reset Trip Point in Stop Mode	With BAT = $3.0V$ (-40°C to +85°C)		3.85		4.25		1, 10
	With BAT = $3.0V$ (0°C to +70°C)		4.4		4.65		1

AC CHARACTERISTICS: EXPANDED BUS MODE TIMING SPECIFICATIONS

 $(V_{CC} = 5V \pm 10\%, T_A = 0^{\circ}C \text{ to } +70^{\circ}C.)$

#	$= 5V \pm 10\%, T_A = 0 C to +70$ PARAMETER		SYMBOL	MIN	MAX	UNITS
1	Oscillator Frequency		$1/t_{\rm CLK}$	1.0	16	MHz
2	ALE Pulse Width		t _{ALPW}	2t _{CLK} - 40		ns
3	Address Valid to ALE Low		t _{AVALL}	t _{CLK} - 40		ns
4	Address Hold After ALE Low	-	t _{AVAAV}	t _{CLK} - 35		ns
5	ALE Low to Valid Instruction In	at 12MHz at 16MHz	t _{ALLVI}		$\frac{4t_{CLK} - 150}{4t_{CLK} - 90}$	ns
6	ALE Low to PSEN Low		t _{ALLPSL}	t _{CLK} - 25		ns
7	PSEN Pulse Width		t _{PSPW}	3t _{CLK} - 35		ns
8	PSEN Low to Valid Instruction	at 12MHz at 16MHz	t _{PSLVI}		3t _{CLK} - 150 3t _{CLK} - 90	ns
9	Input Instruction Hold After PSEN Going High		t _{PSIV}	0	JULK 90	ns
10	Input Instruction Float After PSE	ŭ ŭ	t _{PSIX}		t _{CLK} - 20	ns
11	Address Hold After PSEN Going	g High	t _{PSAV}	t _{CLK} - 8		ns
12	Address Valid to Valid Instruction In	at 12MHz at 16MHz	t _{AVVI}		5t _{CLK} - 150 5t _{CLK} - 90	ns
13	PSEN Low to Address Float	t _{PSLAZ}	0	U CLK	ns	
14	RD Pulse Width	t _{RDPW}	6t _{CLK} - 100		ns	
15	WR Pulse Width		t _{WRPW}	6t _{CLK} - 100		ns
16	$\overline{\text{RD}}$ Low to Valid Data In	at 12MHz at 16MHz	t _{RDLDV}		5t _{CLK} - 165 5t _{CLK} - 105	ns
17	Data Hold After RD High		t _{RDHDV}	0		ns
18	Data Float After RD High		t _{RDHDZ}		2t _{CLK} - 70	ns
19	ALE Low to Valid Data In	at 12MHz at 16MHz	t _{ALLVD}		8t _{CLK} - 150 8t _{CLK} - 90	ns
20	Valid Address to Valid Data In	at 12MHz at 16MHz	- t _{AVDV}		$9t_{CLK} - 165$ $9t_{CLK} - 105$	ns
21	ALE Low to \overline{RD} or \overline{WR} Low		t _{ALLRDL}	3t _{CLK} - 50	$3t_{\text{CLK}} + 50$	ns
22	Address Valid to \overline{RD} or \overline{WR} Low		t _{AVRDL}	4t _{CLK} - 130		ns
23	Data Valid to WR Going Low		t _{DVWRL}	t _{CLK} - 60		ns
24	Data Valid to \overline{WR} High	at 12MHz at 16MHz	t _{DVWRH}	7t _{CLK} - 150 7t _{CLK} - 90		ns
25	Data Valid After WR High	t _{WRHDV}	t _{CLK} - 50		ns	
26	RD Low to Address Float		t _{RDLAZ}		0	ns
27	$\overline{\text{RD}}$ or $\overline{\text{WR}}$ High to ALE High		t _{rdhalh}	t _{CLK} - 40	$t_{CLK} + 50$	ns

EXPANDED PROGRAM-MEMORY READ CYCLE



EXPANDED DATA-MEMORY READ CYCLE



EXPANDED DATA-MEMORY WRITE CYCLE



AC CHARACTERISTICS: EXTERNAL CLOCK DRIVE

 $(V_{CC} = 5V \pm 10\%, T_A = 0^{\circ}C \text{ to } +70^{\circ}C.)$

#	PARAMETER	PARAMETER		MIN	MAX	UNITS		
28	29 External Clask High Time		at 12MHz		+	20		nc
20	28 External Clock-High Time	at 16MHz	t_{CLKHPW}	15		ns		
29	External Clock-Low Time	at 12MHz	+	20		na		
29	External Clock-Low Time	at 16MHz	t_{CLKLPW}	15		ns		
30	External Clock-Rise Time	at 12MHz	+		20	n 0		
30	External Clock-Kise Time	at 16MHz	t _{CLKR}	15		ns		
31	31 External Clock-Fall Time				20			
51		at 16MHz	t _{CLKF}		15	ns		

EXTERNAL CLOCK TIMING



AC CHARACTERISTICS: POWER CYCLE TIME

$(V_{CC} = $	5V ±10%, T _A = 0°C to +70°C.)				
#	PARAMETER	SYMBOL	MIN	MAX	UNITS
32	Slew Rate from V_{CCMIN} to V_{LI}	t _F	130		μs
33	Crystal Startup Time	t _{CSU}		(Note 9)	
34	Power-On Reset Delay	t _{POR}		21,504	t _{CLK}

POWER CYCLE TIMING



AC CHARACTERISTICS: SERIAL PORT TIMING-MODE 0

#	PARAMETER	SYMBOL	MIN	MAX	UNITS
35	Serial-Port Clock-Cycle Time	t _{SPCLK}	$12t_{CLK}$		μs
36	Output-Data Setup to Rising-Clock Edge	t _{DOCH}	10t _{CLK} - 133		ns
37	Output-Data Hold After Rising-Clock Edge	t _{CHDO}	2t _{CLK} - 117		ns
38	Clock-Rising Edge to Input-Data Valid	t _{CHDV}		10t _{CLK} - 133	ns
39	Input-Data Hold After Rising-Clock Edge	t _{CHDIV}	0		ns

SERIAL PORT TIMING-MODE 0



AC CHARACTERISTICS: BYTE-WIDE ADDRESS/DATA BUS TIMING

	$5V \pm 10\%$, $T_A = 0^{\circ}C$ to $+70^{\circ}C$.)				
#	PARAMETER	SYMBOL	MIN	MAX	UNITS
40	Delay to Byte-Wide Address Valid from $\overline{CE1}$, $\overline{CE2}$, or $\overline{CE1N}$ Low During Op Code Fetch	t _{CE1LPA}		30	ns
41	Pulse Width of \overline{CE} 1-4, \overline{PE} 1-4 or $\overline{CE1N}$	t _{CEPW}	4t _{CLK} - 35		ns
42	Byte-Wide Address Hold After $\overline{CE1}$, $\overline{CE2}$, or $\overline{CE1N}$ High During Op Code Fetch	t _{CE1HPA}	2t _{CLK} - 20		ns
43	Byte-Wide Data Setup to $\overline{CE1}$, $\overline{CE2}$, or $\overline{CE1N}$ High During Op Code Fetch	t _{ovce1H}	$1t_{CLK} + 40$		ns
44	Byte-Wide Data Hold After $\overline{CE1}$, $\overline{CE2}$ or $\overline{CE1N}$ High During Op Code Fetch	t _{CE1HOV}	0		ns
45	Byte-Wide Address Hold After \overline{CE} 1-4, \overline{PE} 1-4, or $\overline{CE1N}$ High During MOVX	t _{CEHDA}	4t _{CLK} - 30		ns
46	$\begin{array}{c} \hline \text{Delay from Byte-Wide Address Valid} \\ \hline \hline \hline \text{CE} 1-4, \ \hline \text{PE} 1-4, \ \text{or } \hline \hline \text{CE1N} \ \text{Low During MOVX} \end{array}$	t _{CELDA}	4t _{CLK} - 35		ns
47	Byte-Wide Data Setup to \overline{CE} 1-4, \overline{PE} 1-4, or $\overline{CE1N}$ High During MOVX (read)	t _{DACEH}	$1t_{\text{CLK}} + 40$		ns
48	Byte-Wide Data Hold After \overline{CE} 1-4, \overline{PE} 1-4, or $\overline{CE1N}$ High During MOVX (read)	t _{CEHDV}	0		ns
49	Byte-Wide Address Valid to R/\overline{W} Active During MOVX (write)	t _{AVRWL}	3t _{CLK} - 35		ns
50	Delay from R/\overline{W} Low to Valid Data Out During MOVX (write)	t _{RWLDV}	20		ns
51	Valid Data-Out Hold Time from \overline{CE} 1-4, \overline{PE} 1-4, or $\overline{CE1N}$ High	t _{CEHDV}	1t _{CLK} - 15		ns
52	Valid Data-Out Hold Time from R/\overline{W} High	t _{RWHDV}	0		ns
53	Write Pulse Width (R/\overline{W} Low Time)	t _{RWLPW}	6t _{CLK} - 20		ns

BYTE-WIDE BUS TIMING



RPC AC CHARACTERISTICS: DBB READ $(1/2 - 5)/ \pm 10\%$ T₁ = 0°C to ± 70 °C)

$(V_{CC} = $	$5V \pm 10\%$, $I_A = 0^{\circ}C$ to $\pm 70^{\circ}C$.)				
#	PARAMETER	SYMBOL	MIN	MAX	UNITS
54	$\overline{\text{CS}}$, A ₀ Setup to $\overline{\text{RD}}$	t _{AR}	0		ns
55	$\overline{\text{CS}}$, A ₀ Hold After $\overline{\text{RD}}$	t _{RA}	0		ns
56	RD Pulse Width	t _{RR}	160		ns
57	$\overline{\text{CS}}$, A ₀ to Data-Out Delay	t _{AD}		130	ns
58	$\overline{\text{RD}}$ to Data-Out Delay	t _{RD}	0	130	ns
59	$\overline{\text{RD}}$ to Data-Float Delay	t _{RDZ}		85	ns

RPC AC CHARACTERISTICS: DBB WRITE

 $(V_{CC} = 5V \pm 10\%, T_A = 0^{\circ}C \text{ to } +70^{\circ}C.)$

#	PARAMETER	SYMBOL	MIN	MAX	UNITS
60	$\overline{\text{CS}}$, A_0 Setup to $\overline{\text{WR}}$	t _{AW}	0		ns
61A	$\overline{\text{CS}}$, Hold After $\overline{\text{WR}}$	t _{WA}	0		ns
61B	A_0 , Hold After \overline{WR}	t _{WA}	20		ns
62	WR Pulse Width	t _{WW}	160		ns
63	Data Setup to \overline{WR}	t _{DW}	130		ns
64	Data Hold After WR	t _{WD}	20		ns

AC CHARACTERISTICS: DMA

 $(V_{CC} = 5V \pm 10\%, T_A = 0^{\circ}C \text{ to } +70^{\circ}C.)$

#	PARAMETER	SYMBOL	MIN	MAX	UNITS
65	$\overrightarrow{\text{DACK}}$ to $\overrightarrow{\text{WR}}$ or $\overrightarrow{\text{RD}}$	t _{ACC}	0		ns
66	$\overline{\text{RD}}$ or $\overline{\text{WR}}$ to $\overline{\text{DACK}}$	t _{CAC}	0		ns
67	DACK to Data Valid	t _{ACD}	0	130	ns
68	$\overline{\text{RD}}$ or $\overline{\text{WR}}$ to DRQ Cleared	t _{CRQ}		110	ns

AC CHARACTERISTICS: PROG

 $(V_{CC} = 5V \pm 10\%, T_A = 0^{\circ}C \text{ to } +70^{\circ}C.)$

#	PARAMETER	SYMBOL	MIN	MAX	UNITS
69	PROG Low to Active	t _{PRA}	48		CLKS
70	PROG High to Inactive	t _{PRI}	48		CLKS

RPC TIMING MODE



NOTES:

All parameters apply to both commercial and industrial temperature operation unless otherwise noted.

- 1) All voltages are referenced to ground.
- 2) Maximum operating I_{CC} is measured with all output pins disconnected; XTAL1 driven with t_{CLKR} , $t_{CLKF} = 10$ ns, $V_{IL} = 0.5$ V; XTAL2 disconnected; RST = PORT0 = V_{CC} , MSEL = V_{SS} .
- 3) Idle mode, I_{IDLE} , is measured with all output pins disconnected; XTAL1 driven with t_{CLKR} , $t_{CLKF} = 10$ ns, $V_{IL} = 0.5$ V; XTAL2 disconnected; PORT0 = V_{CC} , RST = MSEL = V_{SS} .
- 4) Stop mode, I_{STOP} , is measured with all output pins disconnected; PORT0 = V_{CC} ; XTAL2 not connected; RST = MSEL = XTAL1 = V_{SS} .
- 5) Pin capacitance is measured with a test frequency: 1MHz, $T_A = +25^{\circ}C$.
- 6) I_{CCO1} is the maximum average operating current that can be drawn from V_{CCO} in normal operation.
- 7) I_{LI} is the current drawn from V_{LI} input when $V_{CC} = 0V$ and V_{CCO} is disconnected.
- 8) V_{CCO2} is measured with $V_{CC} < V_{LI}$, and a maximum load of 10µA on V_{CCO} .
- 9) Crystal startup time is the time required to get the mass of the crystal into vibrational motion from the time that power is first applied to the circuit until the first clock pulse is produced by the on-chip oscillator. The user should check with the crystal vendor for a worst-case specification on this time.
- 10) This parameter applies to industrial temperature operation.
- 11) $\overline{\text{PF}}$ pin operation is specified with $V_{\text{BAT}} \ge 3.0$ V.

PACKAGE INFORMATION

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/DallasPackInfo.)

80-PIN MQFP



44-PIN MQFP



REVISION HISTORY

The following represent the key differences between the 112795 and 073096 version of the DS5001FP data sheet. Please review this summary carefully.

- 1) Change V_{CC02} specification from V_{LI} 0.5 to V_{LI} 0.65 (PCN F62501).
- 2) Update mechanical specifications.

The following represent the key differences between the 073096 and 111996 version of the DS5001FP data sheet. Please review this summary carefully.

1) Change V_{CC01} from V_{CC} - 0.3 to V_{CC} - 0.35.

The following represent the key differences between the 111996 and 061297 version of the DS5001FP data sheet. Please review this summary carefully.

- 1) PF signal moved from V_{OL2} test specification to V_{OL1} . PCN No. (D72502)
- 2) AC characteristics for battery-backed SDI pulse specification added.

The following represent the key differences between the 061297 and 051099 version of the DS5001FP data sheet. Please review this summary carefully.

- 1) Reduced absolute maximum voltage to $V_{CC} + 0.5V$.
- 2) Added note clarifying storage temperature specification is for non-battery-backed state.
- 3) Changed R_{RE} min (industrial temp range) from $40k\Omega$ to $30k\Omega$.
- 4) Changed V_{PFW} max (industrial temp range) from 4.5V to 4.6V.
- 5) Added industrial specification for I_{LI} .
- 6) Reduced t_{CE1HOV} and t_{CEHDV} from 10ns to 0ns.

The following represent the key differences between the 051099 and 052499 version of the DS5001FP data sheet. Please review this summary carefully.

1) Minor markups and ready for approval.

The following represent the key differences between the 052499 and 052302 version of the DS5001FP data sheet. Please review this summary carefully.

- 1) Added information relating to 44-pin package.
- 2) Updated V_{CC01} and I_{CC01} specifications to reflect 0.45V internal voltage drop instead of 0.35V.

The following represent the key differences between the 052302 and 070605 version of the DS5001FP data sheet. Please review this summary carefully.

- 1) Added Pb-free part to Ordering Information table.
- 2) Added operating voltage specification. (This is not a new specification because operating voltage is implied in the testing limits, but rather a clarification.)
- 3) Updated Absolute Maximum Ratings soldering temperature to reference JEDEC standard.

27 of 27

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